NSN 5961-01-009-6314

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Inclosure Material:

Metal

Overall Length:

0.078 inches

Overall Height:

0.040 inches

Overall Width:

0.045 inches

Internal Configuration:

Junction contact

Internal Junction Configuration:

Npn

Mounting Method:

Compression

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

40.0 breakdown voltage, collector-to-base, emitter open and 25.0 breakdown voltage, collector-to-emitter, base open and 2.0 breakdown

voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

150.00 milliamperes source cutoff current

Power Rating Per Characteristic:

360.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

165.0 degrees celsius junction

Terminal Type And Quantity:

4 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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